## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of GLASPER et al

Serial No. 10/520,850

Filed: January 11, 2005

Atty. Ref.: 124-1101

TC/A.U.: 2878

Examiner: T. Ko

For: PHOTODETECTOR CIRCUITS

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December 27, 2006

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

## **INFORMATION DISCLOSURE STATEMENT**

As suggested by 37 C.F.R. 1.97, the undersigned attorney brings to the attention o
the Patent and Trademark Office the references listed on the attached form PTO-1449.
All listed documents are attached.

Opies of U.S. Patent Publications are not required and are not attached.

☑ Listed foreign patent publications and other documents are enclosed.

The listed documents were cited in the ISR and copies should have been supplied by WIPO directly to the US PTO. If copies are not timely received from WIPO, please telephone the undersigned so that copies can be timely supplied for the Examiner's consideration in this US National Phase Application.

This is not to be construed as a representation that a search has been made or that no better prior art exists, or that a reference is relevant merely because cited.

The Examiner is requested to initial the attached form PTO/SB/08a and to return a copy of the initialed document to the undersigned as an indication that the attached references have been considered and made of record.

Pursuant to Rule 37 C.F.R. §1.97(c), a fee of \$180.00 as specified in Rule 17(p) is attached. If there is any shortage in the fee, please charge the deposit account of Nixon & Vanderhye, Account No. 14-1140.

12/28/2006 SZEWDIE1 00000042 10520850

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189.00 OP

Respectfully submitted,

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\*Examiner

this form with next communication to application.

## INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)

ATTY, DOCKET NO

SERIAL NO.

10/520,850

DEC 2.7 2006 THE PROPERTY

124-1101 APPLICANT

GLASPER et al

January 11, 2005

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GROUP

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**Date Considered** 

Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; drawin line through citation if not in conformance and not considered. Initial